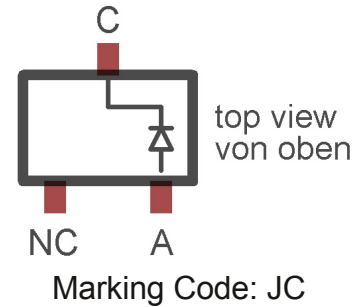


Datasheet

BAL74

Planar Silicon Diode

the BAL74 is a single very fast switching diode for hybrid micro circuits.



Absolute Ratings (Limiting Values)

Continuous Reverse Voltage V_R / V	50
Repetitive Peak Reverse Voltage V_{RRM} / V	60
Forward Current I_F / mA	150
Repetitive Peak Forward Current I_{FRM} / mA	200
Average Forward Current $I_F(AV)$ ($t_p = 10\text{ms}/T=20\text{ms}$) / mA	70
Surge Non Repetitive Forward Current I_{FSM} ($t=1\mu\text{s}$) / mA	4500
Power Dissipation P_{tot} / mW	200
Junction Temperature T_J / °C	150
Storage Temperature T_{STG} / °C	-65, +150

Datasheet

BAL74

Static Electrical Characteristics	
Forward Voltage V_F ($I_F=100\text{mA}$) / V	1
Breakdown Voltage U_{BR} ($I_R=5\mu\text{A}$) / V	60
Reverse Current I_R ($V_R=50\text{V}$) / nA	100
Reverse Current I_R ($V_R=50\text{V}$, $T_j=125^\circ\text{C}$) / μA	100
Dynamic Electrical Characteristics	
Capacitance C ($V_R=0\text{V}$, $f=1\text{MHz}$) / pF	2
Reverse Recovery Time t_{rr} / nS ($I_F=I_R=10\text{mA}$, $i_{tr}=1\text{mA}$)	4
Reverse Recovery Time t_{rr} / nS ($I_F=10\text{mA}$, $V_R=6\text{V}$, $R_L=100\Omega$, $i_{tr}=1\text{mA}$)	2
Thermal Characteristics	
$R_{th(j-a)}$ $^\circ\text{C/W}$	625
$R_{th(j-SR)}$ $^\circ\text{C/W}$	400
Mechanical Data	
Package	TO-236 (1.2x2.9mm)